RUMENTS Data sheet acquired from Harris Semiconductor

SCHS087D - Revised October 2003

CMOS Dual Binary to 1 of 4 **Decoder/Demultiplexers**

High-Voltage Types (20-Volt Rating) CD45558: Outputs High on Select CD4556B: Outputs Low on Select

CD4555B and CD4556B are dual one-of-four decoders/demultiplexers. Each decoder has two select inputs (A and B), an Enable input (E), and four mutually exclusive outputs. On the CD4555B the outputs are high on select; on the CD4556B the outputs are low on select.

When the Enable input is high, the outputs of the CD4555B remain low and the outputs of the CD4556B remain high regardless of the state of the select inputs A and B. The CD4555B and CD4556B are similar to types MC14555 and MC14556, respectively.

The CD4555B and CD4556B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastics packages (E suffix), and 16-lead small-outline packages (M, M96, and MT suffixes). The CD4555B is also supplied in 16-lead small-outline packages (NSR suffix) and 16-lead thin shrink small-outline packages (PW and PWR suffixes.)

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

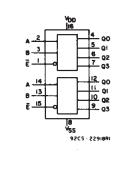
CHARACTERISTIC	V _{DD}	MIN.	MAX.	UNITS
Supply Voltage Range (For T _A = Full Package Temp. Range)	_	3	18	v

MAXIMUM RATINGS. Absolute-Maximum Values:

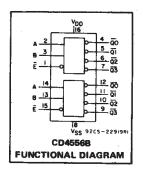
DC SUPPLY-VOLTAGE RANGE, (VDD)
Voltages referenced to VSS Terminal)0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT ±10mA
POWER DISSIPATION PER PACKAGE (PD):
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$
For $T_A = +100^{\circ}C$ to $+125^{\circ}C$ Derate Linearity at $12mW/^{\circ}C$ to $200mW$
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T _A)
STORAGE TEMPERATURE RANGE (Tstg)
LEAD TEMPERATURE (DURING SOLDERING):

Features:

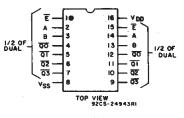
- Expandable with multiple packages
- Standard, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 µA at 18 V over full package temperature range; 100 nA at 18 V and 25°C -
- Noise margin (full package-temperature range): $1 \vee at \vee_{DD} = 5 \vee$ 2 V at V_{DD} = 10 V
- 2.5 V at VDD = 15 V 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices'' Applications:
- Decoding Code conversion
- Demultiplexing (using Enable input as a data input)
- Memory chip-enable selection
- Function selection



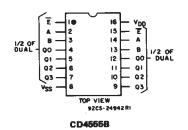
CD45558 FUNCTIONAL DIAGRAM



TERMINAL ASSIGNMENTS



CD4556B



CD4555B, CD4556B Types

CD4555B, CD4556B Types

STATIC ELECTRICAL CHARACTERISTICS

4

14

CHARACTER-	CONE	IS	LIMITS AT INDICATED TEMPER					TURES	UNITS		
ISTIC	Vo	VIN	VDD						+25		UNITS
	(V).	(V)	(V)	55	-40	+85	+125	Min.	Тур.	Max.	
Quiescent Device	_ +	0,5	-5	5	5	150	150		. 0.04	5	· .
Current,	. –	0,10	10	10	10	300	300		0.04	10	
IDD Max.	·	0,15	15	20	20	600	600	10774	0.04	20	μΑ
	_	0,20	20	100	100	3000	3000	ي م تعليد (0.08	100	N 64
Output Low	0,4	0,5	5	0.64	0.61	0.42	.0.36	0.51	1	$\sim n_{\rm eff} = 1$	1. 1. ¹ .
(Sink) Current	. ev Q.5	0,10	10	1.6	1.5	1.1	0.9	1.3	. 2.6	í :	$(a_1) \in \mathbb{R}^n$
IOL Min.	28 1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	<u> </u>	
Output High	-4,6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2		
Current, IOH Min	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	5 mm	See. 1
OH with	13.5	0,15	15	-4.2	-4	-2.8		3.4	-6.8	1 <u>-</u>	1997 - S.C.
Output Voltage:	· –	0,5	5		0	.05		-	0	0.05	· · ·
Low-Level, Voi Max.	-	0,10	10		0	.05	1.10	·	0	0.05	
VUL Max.	_	0,15	15		0	.05	at i	-	0	0.05	v
Output Voltage:		0,5	5		4	.95		4.95	5	7	
High-Level,	-	.0,10	10		9	.95		9,95	10		1.11
VOH Min.	-	0,15	15		14	1.95		14.95	15	-	
Input Low	0.5,4.5	-	5		1	.5		-	-	1.5	
Voltage,	1,9	-	10			3		-	_	3	
VIL Max.	1.5,13.5	· - ·	15			4		-		4	
Input High	0.5,4.5	_	5		3	3.5		3.5		-	
Voltage,	1,9	-	10			7		7		_	
VIH Min.	1.5,13.5	-	15			11		11	-	-	
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μA

DIENT TEMPERATURE (TA)- 25 °C ł 4 LOW (SINK) CU DUTPUT DRAIN-TO-SOURCE VOLTAGE (VDS)-V -----Fig. 1 – Typical output low (sink) current characteristics. AMBIENT TEMPERATURE (TA)-25°C (SINK) CURRENT (I OL) TO- 90 No. DRAIN-TO-SOURCE VOLTAGE (VDS) 92C5 - 243198 Fig. 2 — Minimum output low (sink) current characteristics.

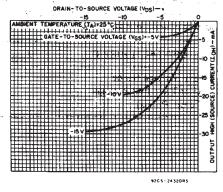
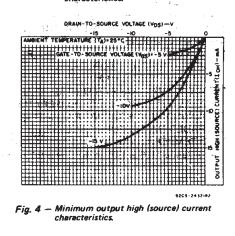


Fig. 3 - Typical output high (source) current characteristics.

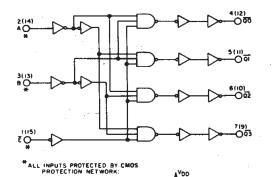


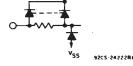
fri fyn y graet

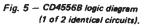
DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$; Input t_p , $t_f = 20$ ns, $C_L = 50 \ pF$, $R_L = 200 \ K\Omega$

199 199 6

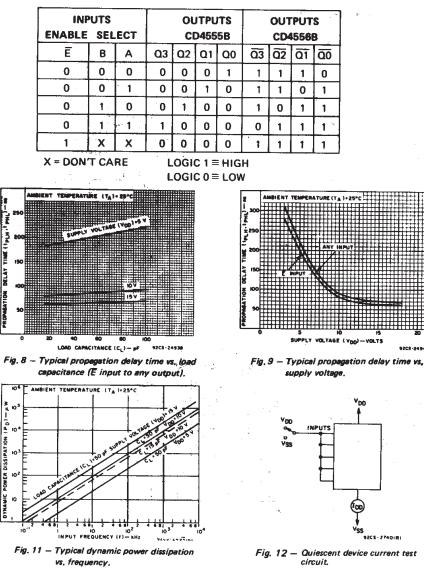
	TEST COND	TIONS	LIM	ITS	
CHARACTERISTIC		V _{DD} Volts	TYP.	MAX.	UNITS
Propagation Delay Time, tpHL,		5	220	440	
A or B Input to ^t PLH		10	95	190	ns
Any Output		15	70	140	
and a second sec	· .		200	400	
E Input to Any		10	85	170	ns
Output		15	65	130	
		5.5	100	200	
Transition Time tTHL, tTLH		10	50	100	ns
$\frac{1}{2} = \frac{1}{2} \left(\frac{1}{2} + \frac{1}{2} \right)^2$		1.5	. 40	80	the second second
Input Capacitance C _{IN}	Any Input		5	7.5	pF







TRUTH TABLE



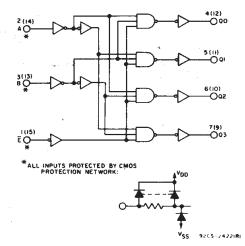


Fig. 6 — CD45558 logic diagram (1 of 2 identical circuits).

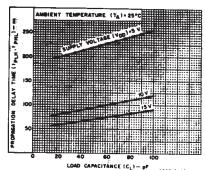


Fig. 7 - Typical propagation delay time vs. load capacitance (A or B input to any output).

9205-24938

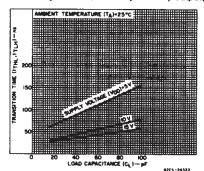


Fig. 10 - Typical transition time vs. load capacitance.

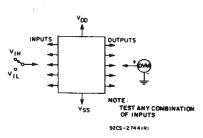


Fig. 13 - Input voltage test circuit.



'D0

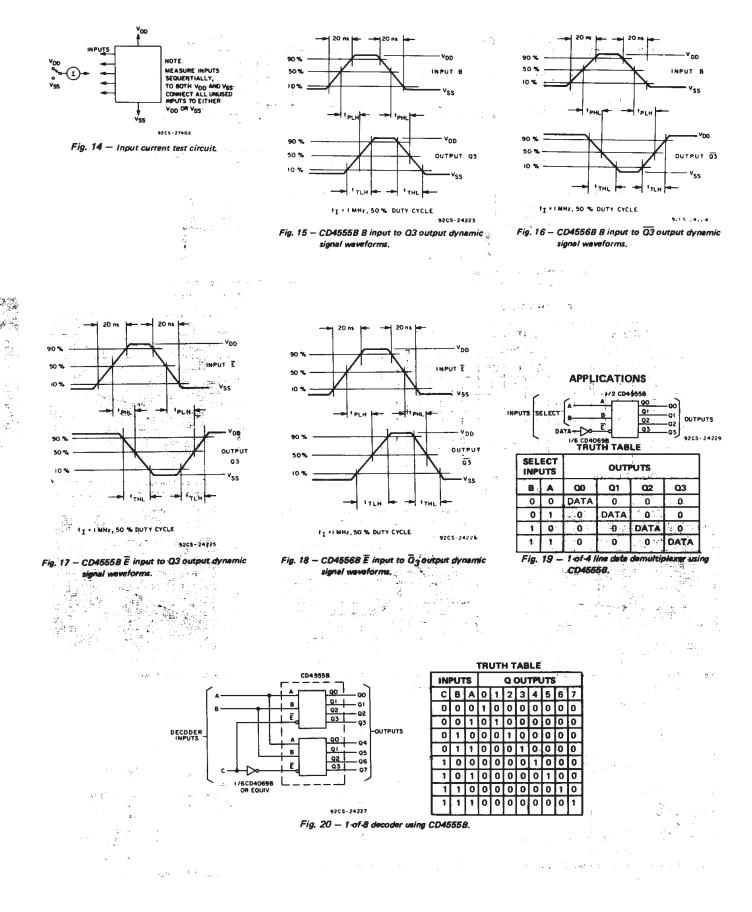
600

Íss

92CS-2740IR

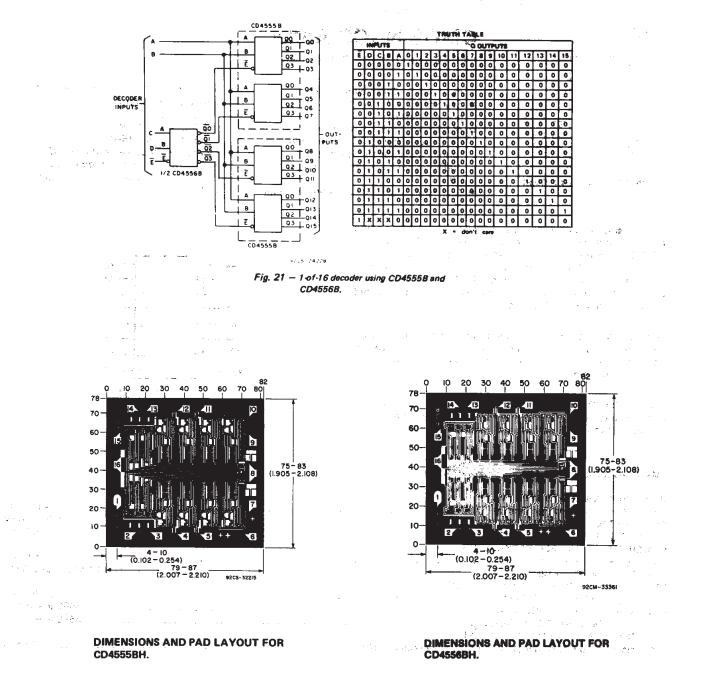
9209-24940

CD4555B, CD4556B Types



2

CD4555B, CD4556B Types



1

19-94

3

COMMERCIAL CMOS HIGH VOLTAGE ICs

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

3-339



22-Jul-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
7704701EA	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	7704701EA CD4555BF3A	Sample
7704801EA	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	7704801EA CD4556BF3A	Samples
CD4555BE	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD4555BE	Samples
CD4555BEE4	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD4555BE	Samples
CD4555BF3A	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	7704701EA CD4555BF3A	Sample
CD4555BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4555BM	Sample
CD4555BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4555BM	Sample
CD4555BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4555BM	Sample
CD4555BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4555B	Sample
CD4555BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM555B	Sample
CD4555BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM555B	Sample
CD4555BPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM555B	Sample
CD4556BE	ACTIVE	PDIP	Ν	16	25	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-55 to 125	CD4556BE	Sample
CD4556BF	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	CD4556BF	Sample
CD4556BF3A	ACTIVE	CDIP	J	16	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	7704801EA CD4556BF3A	Sample
CD4556BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4556BM	Sample
CD4556BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4556BM	Sample



22-Jul-2020

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD4556BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4556BM	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4555B, CD4555B-MIL, CD4556B, CD4556B-MIL :



www.ti.com

PACKAGE OPTION ADDENDUM

22-Jul-2020

• Catalog: CD4555B, CD4556B

• Military: CD4555B-MIL, CD4556B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4555BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4555BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4555BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4556BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

16-Oct-2020



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4555BM96	SOIC	D	16	2500	333.2	345.9	28.6
CD4555BNSR	SO	NS	16	2000	367.0	367.0	38.0
CD4555BPWR	TSSOP	PW	16	2000	853.0	449.0	35.0
CD4556BM96	SOIC	D	16	2500	333.2	345.9	28.6

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2020, Texas Instruments Incorporated